APPLICATION DATA SHEET

Electronic Version v14 Stylesheet Version v14.0

> Title of Invention

High Density Metal Capacitor Using Via Etch Stopping Layer as Field Dielectric in Dual-Damascence Interconnect Process

Application Type:

regular, utility

Attorney Docket Number: 1875.0230001/JDE

Correspondence address:

Customer Number:

26111

26111

Continuing Data:

This is a Continuation of US application number 09/753,664, filed 2001-01-04.

Inventor Information:

Inventor 1:

Applicant Authority Type:

Inventor

Citizenship:

CN

Given Name:

Liming

Family Name:

Tsau

City of Residence:

Irvine

State of Residence:

CA

Country of Residence:

US

Address-1 of Mailing Address:

14591 Fir Avenue

Address-2 of Mailing Address:

City of Mailing Address:

Irvine

State of Mailing Address:

CA

Postal Code of Mailing Address: 92606

Country of Mailing Address:

US

Phone:

Fax:

E-mail:

Attorney Information:	
Autorney information.	
Name	Registration Number